

L Number	Hits	Search Text	DB	Time stamp
-	2	("3890417").PN.	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2002/05/08 17:49
-	2	("4153661").PN.	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2002/05/08 17:49
-	2	("4971736").PN.	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2002/05/08 17:50
-	2	("4373519").PN.	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2002/05/08 17:51
-	2	("4460642").PN.	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2002/05/08 17:52
-	2	("4565663").PN.	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2002/05/08 17:53
-	0	coat and electrode and glass and CPG and porosity and (thickening adj agent) and semiconductor and device	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2002/05/08 17:56
-	0	coat and electrode and glass and CPG and porosity and (thickening and agent) and semiconductor and device	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2002/05/08 17:56
-	2	coat and electrode and glass and particle and porosity and (thickening and agent) and semiconductor and device	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2002/05/08 18:24
-	1	"5663064".PN.	USPAT	2002/05/08 18:23
1320		coated adj semiconductor	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2002/05/08 18:25
-	5	(coated adj semiconductor) and glass and (PTFE)	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2002/05/09 08:18
-	2	("3890417").PN.	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2002/05/09 08:16
-	4	(coated adj semiconductor) and glass and (PTFE) and device	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2002/05/09 08:41
-	0	(coated adj semiconductor adj device) and glass and (PTFE) and layer adj thickness	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2002/05/09 08:42
-	1	(coated adj semiconductor) and glass and (PTFE) and layer adj thickness	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2002/05/09 09:24